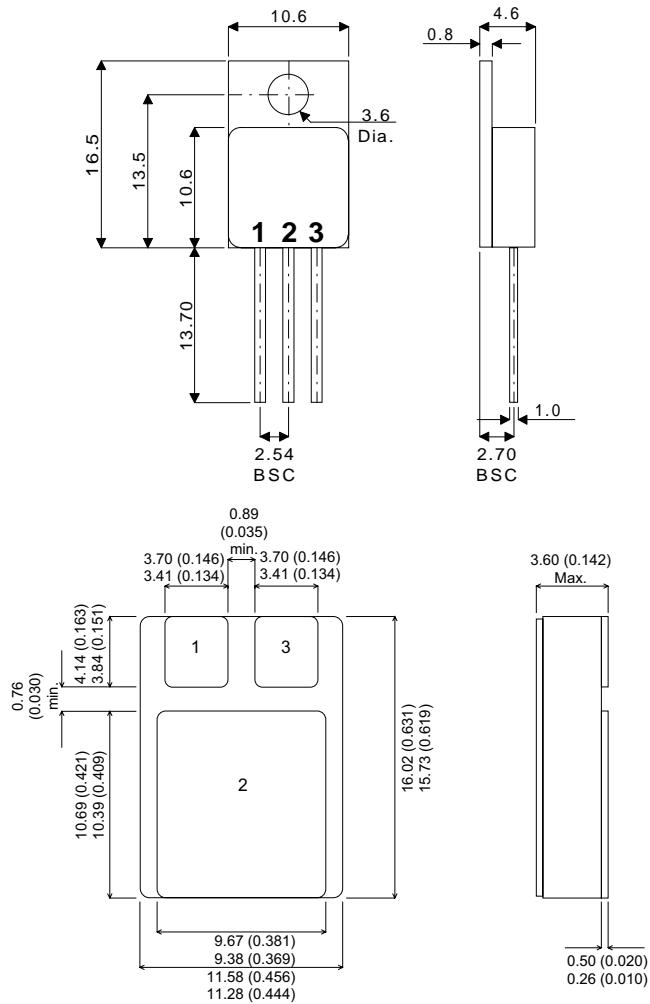


MECHANICAL DATA

Dimensions in mm



TO220M
SMD1

- TO220 Metal Package - Isolated
- Ceramic Surface Mount Package

Pin 1 – Base Pin 2 – Collector Pin 3 – Emitter

| ABSOLUTE MAXIMUM RATINGS ($T_{case}=25^\circ\text{C}$ unless otherwise stated) | | BDS13 | BDS14 | BDS15 |
|--|---|--------------|--------------|--------------|
| V_{CBO} | Collector - Base voltage ($I_E = 0$) | -60V | -80V | -100V |
| V_{CEO} | Collector - Emitter voltage ($I_B = 0$) | -60V | -80V | -100V |
| V_{EBO} | Emitter - Base voltage ($I_C = 0$) | | -5V | |
| I_E , I_C | Emitter , Collector current | | -15A | |
| I_B | Base current | | -5A | |
| P_{tot} | Total power dissipation at $T_{case} \leq 75^\circ\text{C}$ | | 90W | |
| T_{stg} | Storage Temperature | | -65 TO 200°C | |
| T_j | Junction Temperature | | 200°C | |



**SEME
LAB**

BDS13 BDS13SMD
BDS14 BDS14SMD
BDS15 BDS15SMD

ELECTRICAL CHARACTERISTICS ($T_{case} = 25^\circ C$ unless otherwise stated)

| Parameter | Test Conditions | Min. | Typ. | Max. | Unit | |
|-----------------|--|---|--------------------|------|----------------------|---------|
| I_{CBO} | Collector cut-off current ($I_E = 0$) | BDS13 $V_{CB} = -60V$ BDS14 $V_{CB} = -80V$ BDS15 $V_{CB} = -100V$ | | | -500 -500 -500 | μA |
| I_{CEO} | Collector cut-off current ($I_B = 0$) | BDS13 $V_{CE} = -30V$ BDS14 $V_{CE} = -40V$ BDS15 $V_{CE} = -50V$ | | | -1 -1 -1 | mA |
| I_{EBO} | Emitter cut-off current ($I_C = 0$) | $V_{EB} = -5V$ | | | -1 | mA |
| $V_{CEO(sus)*}$ | Collector - Emitter sustaining voltage ($I_B = 0$) | BDS13 BDS14 $I_C = -100mA$ BDS15 | -60 -80 -100 | | | V |
| $V_{CE(sat)*}$ | Collector - Emitter saturation voltage | $I_C = -5A \quad I_B = -0.5A$ $I_C = -10A \quad I_B = -2.5A$ | | | -1 -3 | V |
| $V_{BE(sat)*}$ | Base - Emitter saturation voltage | $I_C = -10A \quad I_B = -2.5A$ | | | -2.5 | V |
| V_{BE*} | Base - Emitter voltage | $I_C = -5A \quad V_{CE} = -4V$ | | | -1.5 | V |
| h_{FE*} | DC Current gain | $I_C = -0.5A \quad V_{CE} = -4V$ $I_C = -5A \quad V_{CE} = -4V$ $I_C = -10A \quad V_{CE} = -4V$ | 40 15 5 | | 250 150 | |
| f_T | Transition frequency | $I_C = -0.5A \quad V_{CE} = -4V$ | 3 | | | MHz |

*Pulsed : Pulse duration = 300 μs , duty cycle = 1.5%

SWITCHING CHARACTERISTICS

| Parameter | Test Conditions | Max. | Unit |
|-----------|-------------------------|------|---------|
| t_{on} | On Time ($t_d + t_r$) | 0.7 | μs |
| t_s | Storage Time | 1.0 | μs |
| t_r | Fall Time | | |

THERMAL DATA

| | | |
|-------------------|---------------------------------------|--------------|
| $R_{THj-case}$ | Thermal resistance junction - case | Max. 1.4°C/W |
| $R_{THcase-sink}$ | Thermal resistance case - heatsink ** | Typ. 1.0°C/W |
| R_{THj-a} | Thermal resistance junction - ambient | Max. 80°C/W |

** Smooth flat surface using thermal grease.